

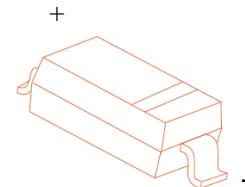


SHENZHEN HAOHUI MICRO-ELECTRONICS CO.,LTD

## SOD-123 Plastic-Encapsulate Diodes

**1N4148W** FAST SWITCHING DIODE**FEATURES**

- Fast Switching Speed
- Surface Mount Package Ideally Suited for Automatic Insertion
- For General Purpose Switching Applications
- High Conductance

**MARKING: T4****SOD-123****Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25°C**

Parameter	Symbol	Limit		Unit
<b>Non-Repetitive Peak Reverse Voltage</b>	V <sub>RM</sub>	100		V
<b>Peak Repetitive Peak Reverse Voltage</b>	V <sub>RRM</sub>			
<b>Working Peak Reverse Voltage</b>	V <sub>RWM</sub>	100		V
<b>DC Blocking Voltage</b>	V <sub>R</sub>			
<b>RMS Reverse Voltage</b>	V <sub>R(RMS)</sub>	71		V
<b>Forward Continuous Current</b>	I <sub>FM</sub>	300		mA
<b>Average Rectified Output Current</b>	I <sub>o</sub>	150		mA
<b>Peak Forward Surge Current @t=1.0μs @t =1.0s</b>	I <sub>FSM</sub>	2.0		A
		1.0		
<b>Power Dissipation</b>	P <sub>d</sub>	500		mW
<b>Thermal Resistance from Junction to Ambient</b>	R <sub>θJA</sub>	250		°C/W
<b>Junction Temperature</b>	T <sub>j</sub>	150		°C
<b>Storage Temperature</b>	T <sub>STG</sub>	-55~+150		°C

**Electrical Ratings @Ta=25°C**

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
<b>Forward voltage</b>	V <sub>F1</sub>			0.715	V	I <sub>F</sub> =1mA
	V <sub>F2</sub>			0.855	V	I <sub>F</sub> =10mA
	V <sub>F3</sub>			1.0	V	I <sub>F</sub> =50mA
	V <sub>F4</sub>			1.25	V	I <sub>F</sub> =150mA
<b>Reverse current</b>	I <sub>R1</sub>			1	μA	V <sub>R</sub> =75V
	I <sub>R2</sub>			25	nA	V <sub>R</sub> =20V
<b>Capacitance between terminals</b>	C <sub>T</sub>			2	pF	V <sub>R</sub> =0V,f=1MHz
<b>Reverse recovery time</b>	t <sub>rr</sub>			4	ns	I <sub>F</sub> =I <sub>R</sub> =10mA I <sub>rr</sub> =0.1XI <sub>R</sub> ,R <sub>L</sub> =100Ω

# Typical Characteristics

1N4148W

